



HMC336MS8G / 336MS8GE

GaAs MMIC SPDT NON-REFLECTIVE POSITIVE CONTROL SWITCH, DC* - 6.0 GHz

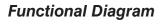
Typical Applications

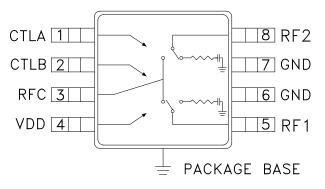
This switch is suitable for usage in DC - 6.0 GHz 50-Ohm or 75-Ohm systems:

- Broadband
- Fiber Optics
- Switched Filter Banks
- Wireless below 6.0 GHz

Features

Broadband Performance: DC - 6.0 GHz High Isolation: 42 dB@ 6 GHz Low Insertion Loss: 1.6 dB@ 6 GHz MSOP8G SMT Package





General Description

The HMC336MS8G & HMC336MS8GE are broadband non-reflective GaAs MESFET SPDT switches in low cost 8 lead MSOP8G surface mount packages with an exposed ground paddle. Covering DC to 6.0 GHz, this switch offers high isolation and low insertion loss. The switch operates using a positive control voltage of 0/+5 Volts, and requires a fixed bias of +5V. This switch is suitable for usage in 50-Ohm or 75-Ohm systems.

Electrical Specifications, $T_A = +25^{\circ}$ C, With 0/+5V Control, 50 Ohm System

Parameter		Frequency	Min.	Тур.	Max.	Units
Insertion Loss		DC - 2.0 GHz DC - 4.0 GHz DC - 6.0 GHz		1.2 1.4 1.6	1.6 1.8 2.0	dB dB dB
Isolation		DC - 2.0 GHz DC - 4.0 GHz DC - 6.0 GHz	42 39 37	47 44 42		dB dB dB
Return Loss	"On State"	DC - 2.0 GHz DC - 6.0 GHz	9 6	12 9		dB dB
Return Loss (RF1, RF2)	"Off State"	2.0 - 6.0 GHz	13	18		dB
Input Power for 1 dB Compression		0.5 - 6.0 GHz	20	25		dBm
Input Third Order Intercept (Two-Tone Input Power = +7 dBm Each Tone, 1 MHz Tone Spacing)		0.5 - 6.0 GHz	37	42		dBm
Switching Characteristics tRISE, tFALL (10/90% RF) tON, tOFF (50% CTL to 10/90% RF)		DC - 6.0 GHz		8 20		ns ns

* DC blocking capacitors are required at ports RFC, RF1 and RF2. Their value will determine the lowest transmission frequency.

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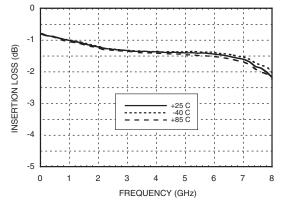


RoHS V

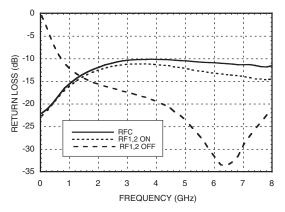
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Isolation

Insertion Loss vs. Temperature

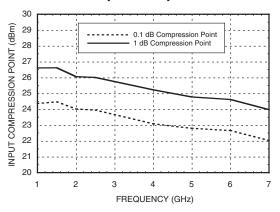


Return Loss

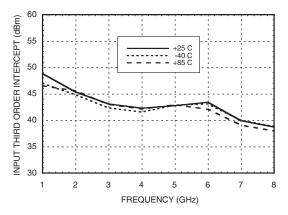


0 -10 -20 _____ RF1 **ISOLATION (dB)** -30 -40 -50 -60 -70 0 2 3 6 8 4 5 7 1 FREQUENCY (GHz)

0.1 and 1 dB Input Compression Point



Input Third Order Intercept Point



For price, delivery, and to place orders, please contact Hittite Microwave Corporation: 20 Alpha Road, Chelmsford, MA 01824 Phone: 978-250-3343 Fax: 978-250-3373 Order On-line at www.hittite.com





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Absolute Maximum Ratings

Bias Voltage Range (Vdd)	+7.0 Vdc
Control Voltage Range (A & B)	-0.5V to Vdd +1.0 Vdc
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
Maximum Input Power	+28 dBm
ESD Sensitivity (HBM)	Class 1A

Note:

DC blocking capacitors are required at ports RFC and RF1, 2. Their value will determine the lowest transmission frequency.



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Bias Voltage & Current

Vdd	ldd (Typ.)	ldd (Max.)
(Vdc)	(μΑ)	(μΑ)
+5.0	35	

Control Voltages

State	Bias Condition
Low	0 to 0.2 Vdc @ 35 μA Typical
High	+5 Vdc @ 10 μA Typical

Truth Table

Control Input		Signal Path State
А	В	RFCOM to:
Low	High	RF1
High	Low	RF2

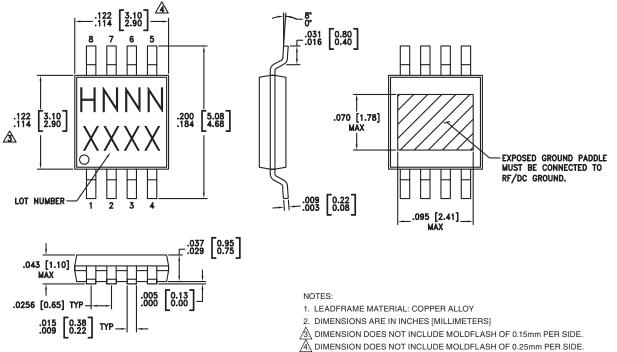




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EARTH FRIENDLY

Outline Drawing



 JIMENSION DOES NOT INCLODE MOLDFLAGH OF 0.231111 FER SIDE.
ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking ^[3]
HMC336MS8G	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 ^[1]	H336 XXXX
HMC336MS8GE	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 ^[2]	<u>H336</u> XXXX

[1] Max peak reflow temperature of 235 $^\circ\text{C}$

[2] Max peak reflow temperature of 260 $^\circ\text{C}$

[3] 4-Digit lot number XXXX



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Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	CTLA	See truth table and control voltage table.	0R
2	CTLB	See truth table and control voltage table.	± c ±
3, 5, 8	RFC, RF1, RF2	This pin is DC coupled and matched to 50 Ohm. Blocking capacitors are required.	
4	VDD	Supply Voltage. This pin may be left floating with degradation of power performance by approximately 1.5 dB.	
6, 7	GND	Package bottom has exposed metal paddle that must also be connected to PCB RF ground.	

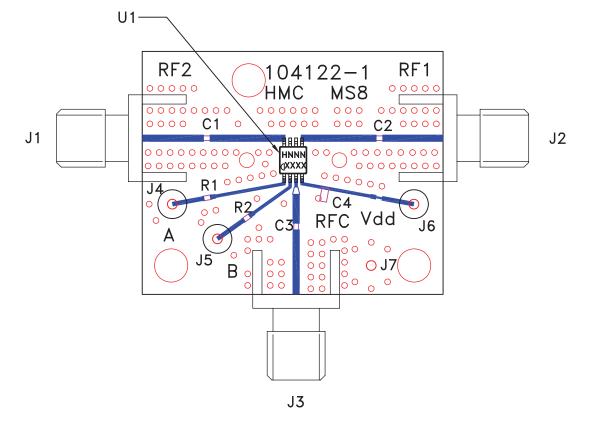




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Evaluation PCB



List of Materials for Evaluation PCB 104124 [1]

Item	Description	
J1 - J3	PCB Mount SMA RF Connector	
J4 - J7	DC Pin	
C1 - C3	100 pF Capacitor, 0402 Pkg.	
C4	10k pF Capacitor, 0603 Pkg.	
R1 - R2	100 Ohm Resistor, 0402 Pkg.	
U1	HMC336MS8G / HMC336MS8GE SPDT Switch	
PCB [2]	104122 Evaluation PCB 1.05"x1.30"	

Reference this number when ordering complete evaluation PCB
Circuit Board Material: Rogers 4350

The circuit board used in the final application should be generated with proper RF circuit design techniques. Signal lines at the RF port should have 50 ohm impedance and the package ground leads and backside ground slug should be connected directly to the ground plane similar to that shown above. The evaluation circuit board shown above is available from Hittite Microwave Corporation upon request.